

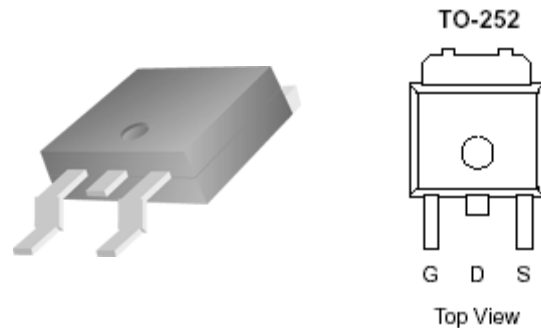
## N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low  $r_{DS(on)}$  provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe DPAK saves board space
- Fast switching speed
- High performance trench technology



PRODUCT SUMMARY		
$V_{DS}$ (V)	$r_{DS(on)}$ m( $\Omega$ )	$I_D$ (A)
30	4.5 @ $V_{GS} = 10V$	87
	5.5 @ $V_{GS} = 4.5V$	78



ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)			
Parameter	Symbol	Limit	Units
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current <sup>a</sup>	$T_C=25^\circ\text{C}$ $I_D$	87	A
Pulsed Drain Current <sup>b</sup>	$I_{DM}$	71	
Continuous Source Current (Diode Conduction) <sup>a</sup>	$I_S$	30	A
Power Dissipation <sup>a</sup>	$T_C=25^\circ\text{C}$ $P_D$	50	W
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to 175	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient <sup>a</sup>	$R_{\theta JA}$	50	$^\circ\text{C/W}$
Maximum Junction-to-Case	$R_{\theta JC}$	3.0	$^\circ\text{C/W}$

### Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

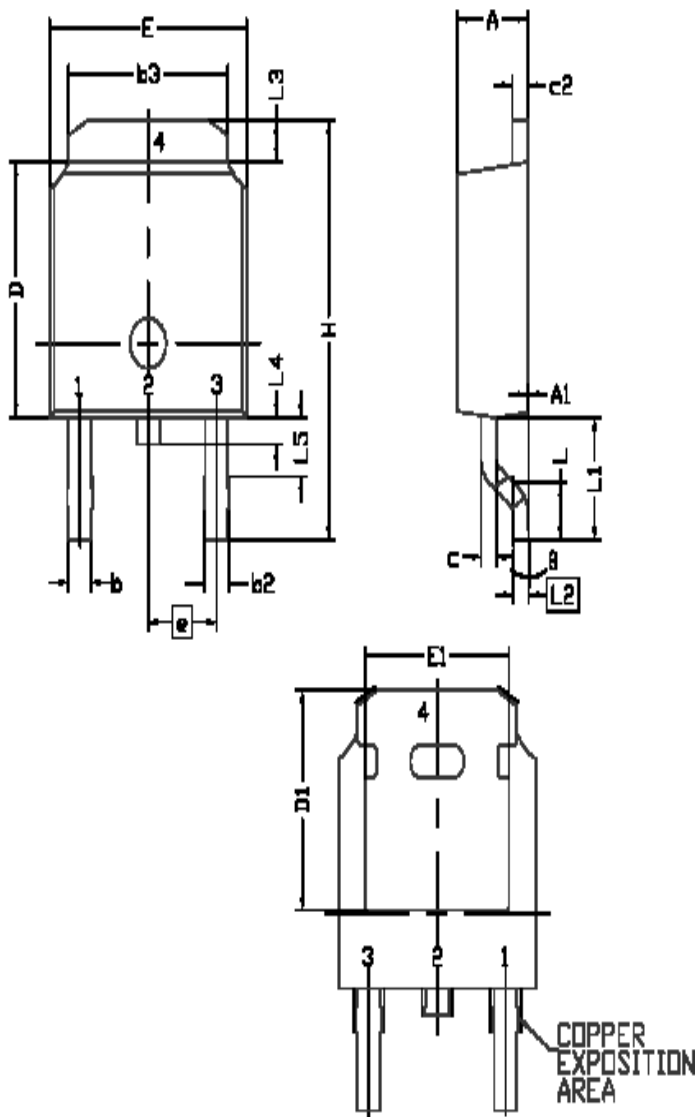
SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Conditions	Limits			Unit
			Min	Typ	Max	
<b>Static</b>						
Gate-Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	1		3	V
Gate-Body Leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = 20 V			±100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 24 V, V <sub>GS</sub> = 0 V			1	μA
		V <sub>DS</sub> = 24 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55°C			25	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	V <sub>DS</sub> = 5 V, V <sub>GS</sub> = 10 V	34			A
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 7 A			4.5	mΩ
		V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 6 A			5.5	
Forward Transconductance <sup>A</sup>	g <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 7 A		22		S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = 7 A, V <sub>GS</sub> = 0 V		1.1		V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 7 A		70		nC
Gate-Source Charge	Q <sub>gs</sub>			10		
Gate-Drain Charge	Q <sub>gd</sub>			30		
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1MHz		6000		pF
Output Capacitance	C <sub>oss</sub>			1000		
Reverse Transfer Capacitance	C <sub>rss</sub>			700		
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 25 V, R <sub>L</sub> = 25 Ω, I <sub>D</sub> = 7 A, V <sub>GEN</sub> = 10 V		20		nS
Rise Time	t <sub>r</sub>			40		
Turn-Off Delay Time	t <sub>d(off)</sub>			200		
Fall-Time	t <sub>f</sub>			100		

## Notes

- Pulse test: PW ≤ 300μs duty cycle ≤ 2%.
- Guaranteed by design, not subject to production testing.

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# Package Information



SYMBOL	DIMENSIONAL REQMTS		
	MIN	NOM	MAX
E	6.40	6.60	6.731
L	1.40	1.52	1.77
L1	2.743 REF		
L2	0.508 BSC		
L3	0.89	—	1.27
L4	0.64	—	1.01
L5	—	—	—
D	6.00	6.10	6.223
H	9.40	10.00	10.40
b	0.64	0.76	0.88
b2	0.77	0.84	1.14
b3	3.21	3.34	3.46
e	2.286 BSC		
A	2.20	2.30	2.38
A1	0	—	0.127
c	0.45	0.50	0.60
c2	0.45	0.50	0.58
D1	5.30	—	—
E1	4.40	—	—
θ	0°	—	10°